said main emitters of said power semiconductor elements are pressed by said platelike emitter electrode terminal so that said main emitters and said emitter electrode terminal are electrically connected together.

30. (New) The voltage-driven power semiconductor device according to claim 29, wherein at least those power semiconductor elements connected in series have overvoltage protective circuits.--.

## **REMARKS**

Consideration of the present application in light of the following discussion is respectfully requested.

Claims 23-30 are presently active in the case, with Claims 19-22 cancelled and with Claims 23-30 added, by way of the present amendment, without was is believed to be the introduction of new matter.

The present amendment present Claims 23-30 for prosecution on the merits.

Consequently, Claims 23-30 are ready for examination on the merits. An early and favorable is action is respectfully requested.

Respectfully submitted,

OBLON, SPIVAK, McCLELLAND,

MAIER & NEUSTADT, P.C.

Gregory J. Maier

Registration No. 25,599 Attorney of Record

Carlos R. Villamar

Registration No. 43,224

22850

(703) 413-3000

Fax #: (703) 413-2220

I:\atty\CRV\0039\198092.supre; GJM:CRV/abs